

Supplementary materials for

## **Multifunctional amorphous FeCoNiTi<sub>x</sub>Si high-entropy alloys with excellent electromagnetic-wave absorption performances**

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## Supplementary Table and Figures

**Table S1** Melting point, Crystal structure, and atomic radius.

Element	Fe	Co	Ni	Ti	Si
Melting point (°C)	1538	1495	1455	1668	1414
Crystal structure	BCC	HCP	FCC	HCP	FCC
Atomic radius (pm)	126	125	124	147	111

$$\Omega = \frac{T\Delta S_{mix}}{|\Delta H_{mix}|} \quad (\text{S1})$$

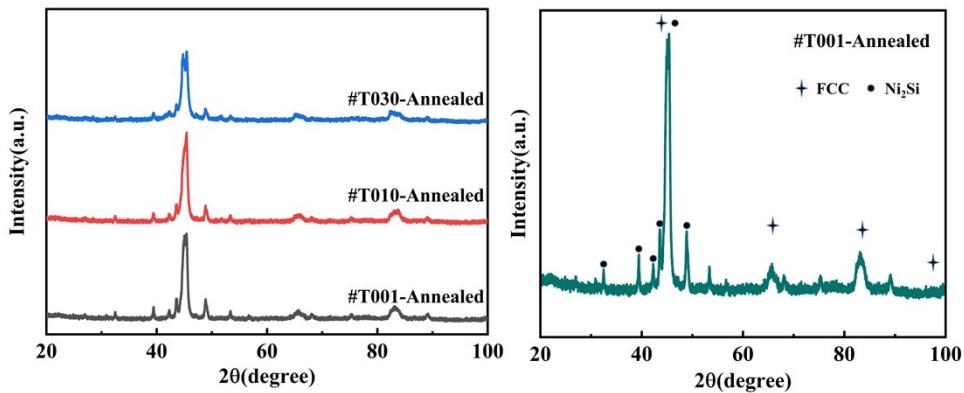
$$\delta = \sqrt{\sum_{i=1}^n c_i (1 - r_i / \bar{r})^2} \quad (\text{S2})$$

$$VEC = \sum_i^n c_i (VEC)_i \quad (\text{S3})$$

Where  $c_i$  is the mole fraction of element i.  $\bar{r}$  and  $T_m$  are the average atomic radius and the melting point of the alloy, respectively. The  $\Delta H_{ij}^{mix}$  represents the mixing enthalpy of a binary system of equimolar composition in the liquid phase.

**Table S2** Grain sizes, internal stress, the crystallinity and lattice constant of samples

Samples	#T001	#T010	#T030
Grain size (nm)	10.2	12	12.8
Intrinsic strain ( $\epsilon \times 10^{-3}$ )	0.892	0.768	0.718
Crystallinity(%) - BCC	57.15	59.95	64.51
Lattice Constant(A) - BCC	4.0508	4.0509	4.3609



**Fig. S1** XRD diagram of #T001, #T010, and #T030 after annealing.

**Table S3** Binary mixing enthalpies for each atom pair in Fe–Co–Ni–Ti–Si alloys.

$\Delta H_{ij}^{mix}$ (kJ×mol <sup>-1</sup> )				
Fe	-1	-2	-17	-35
/	Co	0	-28	-38
/	/	Ni	-35	-40
/	/	/	Ti	-45
/	/	/	/	Si

**Table S4** Chemical Compositions of samples #T001, #T010, #T030, #T100 and #T200.

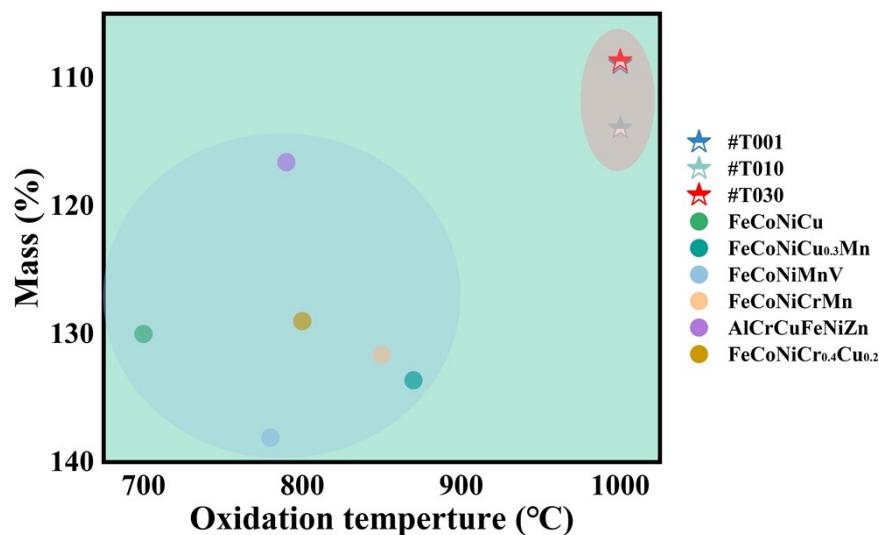
Samples	Atomic percent(%)				
	Fe	Co	Ni	Ti	Si
#T001	27.49	27.77	25.92	0.34	18.48
#T010	26.18	26.89	24.58	2.5	19.85
#T030	26.08	23.83	22.50	8.86	18.72
#T100	23.19	21.64	20.27	19.76	15.14
#T200	33.41	17.27	17.17	33.41	12.91

**Table S5** Electrochemical parameters of equivalent circuit under different stray current densities.

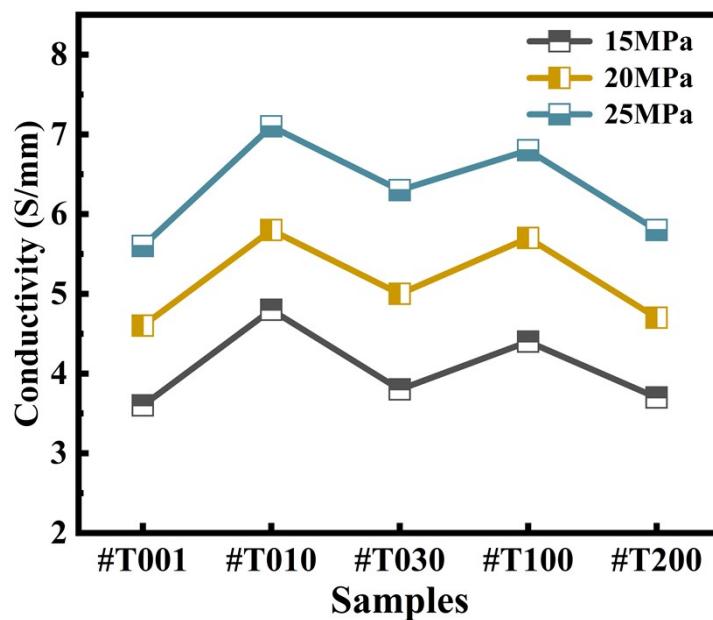
Samples	R <sub>s</sub> (Ω cm <sup>2</sup> )	CPE <sub>1</sub> -T μΩ <sup>-1</sup> cm <sup>2</sup> s <sup>p</sup> )	CPE <sub>1</sub> -P (F/cm)	CPE <sub>2</sub> -T (μΩ <sup>-1</sup> cm <sup>2</sup> s <sup>p</sup> )	CPE <sub>2</sub> -P (F/cm)	R <sub>ct1</sub>	R <sub>ct2</sub>
#T001	4.088	0.00034277	0.67895	0.00017381	0.92338	127.6	33639
#T010	3.308	0.00026379	0.67015	0.00016832	0.91616	109.1	129390
#T030	3.584	0.00030884	0.67077	0.00018296	0.86741	123.9	694680

#T100	3.768	0.0003933	0.70339	0.00017699	0.88591	63.22	1.202E7
#T200	3.575	0.00024919	0.67073	0.00015231	0.90477	84.9	300370

Rs represents the solution resistance, CPE<sub>1</sub> the double-layer capacitance at the passivation film/material interface, R<sub>ct</sub>1 the electrochemical transfer resistance, CPE<sub>2</sub> the passivation film capacitance, and R<sub>ct</sub>2 the ion transport resistance in the passivation film.



**Fig. S2** The comparison of oxidation resistance properties with other related materials.<sup>1-6</sup>



**Fig. S3** Conductivity of FeCoNiTi<sub>x</sub>Si ( $x = 0.01, 0.1, 0.3, 1$  and  $2$ ) HEAs powders under different pressures.

**Table S6** The detailed conductivity of FeCoNiTi<sub>x</sub>Si ( $x = 0.01, 0.1, 0.3, 1$ , and  $2$ ) HEAs under different pressures.

Pressure (MPa)	Conductivity (S/mm)				
	#T001	#T010	#T030	#T100	#T200
15	3.6	4.8	3.8	4.4	3.7
20	4.6	5.8	5	5.7	4.7
25	5.6	7.1	6.3	6.8	5.8

**Table S7** The detailed data of EMW absorption properties of FeCoNiTixSi ( $x = 0.01, 0.1, 0.3, 1$ , and  $2$ ) HEAs in the 2–18 GHz range.

Samples	RL <sub>min</sub> (dB)	Frequency (GHz)	d <sub>min</sub>	Bandwidth (GHz)	RL<-10 dB	d (mm)
#T001	-68.4	6.14	3.08	5.15	11.67-16.82	1.69
#T010	-28.3	8.96	2.76	3.68	9.86-13.54	2.31
#T030	-30.5	10.80	2.32	4.03	11.48-15.51	1.94
#T100	-63.4	9.12	2.18	3.64	13.80-17.45	1.42
#T200	-21.3	18	4	-	-	-

**Table S8** The comparison of comprehensive properties with related materials.

	RL <sub>min</sub> (dB)	EMB (GHz)	d <sub>m</sub> (mm)	Nanohardness (Gpa)	i <sub>corr</sub> (μA/cm <sup>2</sup> )	Ref.
#T001	-68.4	5.12	1.69	3.97	1.64	This work
#T100	-63.4	3.64	1.42	3.07	1.49	This work
FeSi	-19.3	3.9	3.03	-	-	Ref. 40
FeSiAl	-39.7	0.85	4	-	-	Ref. 36
FeCoNiCrMn	-	-	-	2.35	-	Ref. 43
FeCoNiCuAlCe <sub>0.09</sub>	-	-	-	-	4.01	Ref. 46
FeCrMoNiPBCSi	-60.3	2.3	3.55	-	-	Ref. 16
FeCoNiMn <sub>0.5</sub> Al <sub>0.4</sub>	-42.9	4.4	3	-	-	Ref. 38
Fe <sub>77.6</sub> Si <sub>12.3</sub> Al <sub>10.1</sub>	-22.2	6	2	-	-	Ref. 35
FeCoNiCuTi <sub>0.2</sub>	-47.8	4.76	2.16	-	0.949	Ref. 15
FeCoNiCuC <sub>0.04</sub>	-61.1	5.1	1.72	3.42	5.14	Ref. 41
FeCoNi(Si <sub>0.6</sub> Al <sub>0.2</sub> B <sub>0.2</sub> )	-44.1	3.8	2	-	-	Ref. 44
Ti <sub>21.6</sub> Al <sub>11.3</sub> Cr <sub>19.4</sub> Si <sub>23.5</sub> V <sub>22.0</sub> O <sub>2.2</sub>	-	-	-	-	6.14	Ref. 39
HCNs	-45.7	3.9	3.6	-	-	Ref. 34
Co <sub>4</sub> Fe <sub>6</sub>	38.7	6.9	2	-	-	Ref. 45
Mg <sub>65</sub> Ni <sub>20</sub> Nd <sub>15</sub>	-	-	-	3.4	-	Ref. 42
FeCoNiMn <sub>0.5</sub> Al <sub>0.2</sub>	-44.4	3.825	3	3.97	-	Ref. 37

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